# INJ0003AX SERIES

PRELIMINARY

## DESCRIPTION

INJ0003AX is a Silicon P-channel MOSFET.

This product is most suitable for low voltage use such as portable machinery, because of low voltage drive and low on resistance.

# FEATURE

•Input impedance is high, and not necessary to consider a drive electric current.

·Vth is low, and drive by low voltage is possible. Vth=-0.6~-1.2V

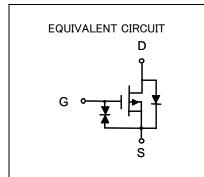
•Low on Resistance. Ron= $2\Omega(TYP)$ 

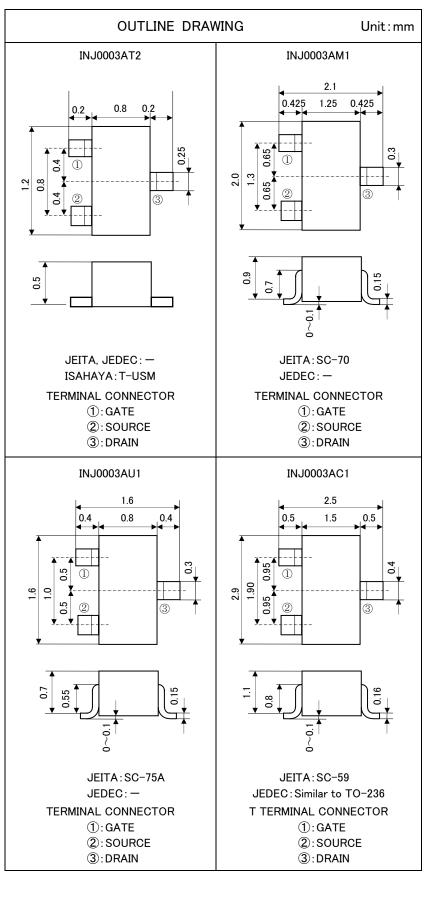
•High speed switching.

•Small package for easy mounting.

## APPLICATION

high speed switching , Analog switching





ISAHAYA ELECTRONICS CORPORATION

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# PRELIMINARY

Notice: This is not a final specification Some parametric are subject to change.

High speed switching Silicon P-channel MOSFET

# MAXIMUM RATING(Ta=25°C)

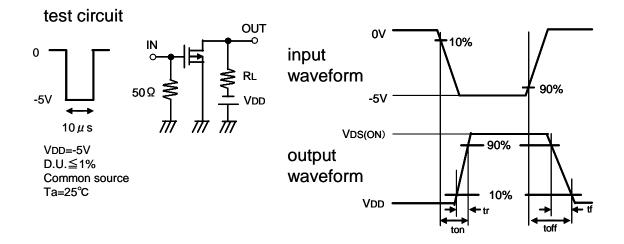
SYMBOL	PARAMETER	RATING				
	FARAMETER	INJ0003AT2	INJ0003AU1	INJ0003AM1	INJ0003AC1	UNIT
V <sub>DSS</sub>	Drain-source voltage	-20				
V <sub>GSS</sub>	Gate-source voltage	$\pm 8$				
I <sub>D</sub>	Drain current	-200				
P <sub>D</sub>	Total power dissipation (Ta=25°C)	125(※)	150	200		mW
Tch	Channel temperature	+125	+150			
Tstg	Range of Storage temperature	-55~+125	-55~+150			°C

### ELECTRICAL CHARACTERISTICS (Ta=25°C)

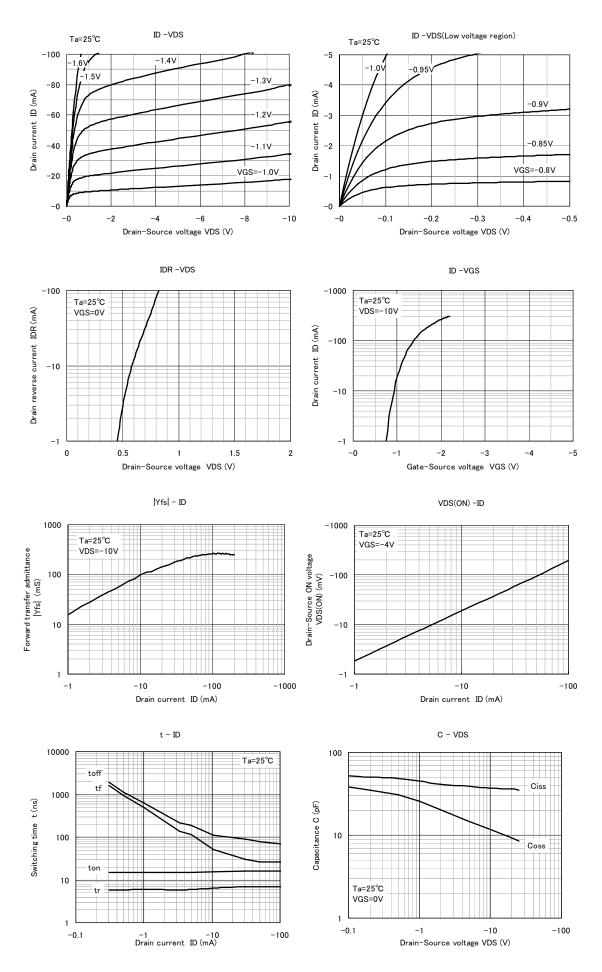
 $\label{eq:package mounted on 9mm \times 19mm \times 1mm glass-epoxy substrate.}$ T I IMIT Τ

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
V <sub>(BR)DSS</sub>	Drain-source breakdown voltage	$I_{D}$ =-100 $\mu$ A, V <sub>GS</sub> =0V	-20	-	-	V
I <sub>GSS</sub>	Gate-source leak current	$V_{gs} = \pm 5V, V_{ds} = 0V$	-	_	±0.5	μA
IDSS	Zero gate voltage drain current	V <sub>DS</sub> =-20V ,V <sub>GS</sub> =0V	-	-	-50	μA
$V_{\text{th}}$	Gate threshold voltage	$I_{D}$ =-250 $\mu$ A, V <sub>DS</sub> = V <sub>GS</sub>	-0.6	-	-1.2	V
Y <sub>fs</sub>	Forward transfer admittance	V <sub>DS</sub> =-10V, I <sub>D</sub> =-0.1A	-	280	-	mS
R <sub>DS(ON)</sub>	Static drain-source on-state resistance	I <sub>D</sub> =-100mA, V <sub>GS</sub> =-4.0V	-	2	-	Ω
Ciss	Input capacitance	$V_{DS}$ =-10V, $V_{GS}$ =0V,f=1MHz	-	37	-	pF
Coss	Output capacitance	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,f=1MHz	-	12	-	pF
ton	Curitalian tina	V <sub>DD</sub> =-5V , I <sub>D</sub> =-10mA V <sub>GS</sub> =0~-5V	-	16	-	ns
toff	- Switching time		-	110	-	

# Switching time test condition



# **TYPICAL CHARACTERISTICS**



ISAHAYA ELECTRONICS CORPORATION



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